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September 2016

FPF1504 / FPF1504L Advanced Load Management Switch

Features

- 1.0 V to 3.6 V Input Voltage Operating Range
- Typical R_{DS(ON)}:
 - 15 mΩ at V_{IN}=3.3 V
 - $20 \text{ m}\Omega$ at $V_{IN}=1.8 \text{ V}$
 - $40 \text{ m}\Omega$ at $V_{IN}=1.0 \text{ V}$
- Slew Rate Control
- Output Discharge Function
- Low <1 µA Quiescent Current at V_{ON}=V_{IN}
- ESD Protected: 4000 V HBM, 2000 V CDM
- GPIO/CMOS-Compatible Enable Circuitry
- Active HIGH and active LOW versions

Applications

- Mobile Devices and Smart Phones
- Portable Media Devices
- Digital Cameras
- Advanced Notebook, UMPC, and MID
- Portable Medical Devices
- GPS and Navigation Equipment

Description

The FPF1504/FPF1504L are low-R_{DS} P-channel MOSFET load switches of the IntelliMAX™ family. Integrated slew-rate control prevents excessive inrush current from the supply rails with capacitive loads common in power applications. In addition, the FPF1504/FPF1504L feature output discharge capability.

The input voltage range operates from 1.0 V to 3.6 V to fulfill today's mobile device supply requirements. Switch control is by a logic input (ON pin) capable of interfacing directly with low-voltage CMOS control signals and GPIOs in embedded processors.

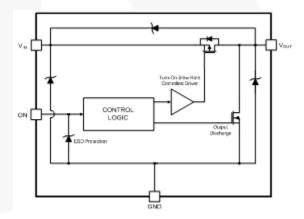


Figure 1. Block Diagram

Ordering Information

| Part Number | Top Mark | Switch (Typical) At 1.8 V _{IN} | Input Buffer | Output Discharge | ON Pin Activity | Package |
|--------------|-------------|---|-----------------|---------------------|--------------------|--|
| FPF1504UCX | G4 | 20 mΩ | CMOS | YES | Active HIGH | 4-Ball, WLCSP, 0.5 mm Pitch |
| FPF1504BUCX | G4 | 20 mΩ | CMOS | YES | Active HIGH | 4-Ball, WLCSP with Backside Laminate, 0.5 mm Pitch |
| FPF1504LUCX | GZ | 20 mΩ | CMOS | YES | Active LOW | 4-Ball, WLCSP, 0.5 mm Pitch |
| FPF1504LBUCX | GZ | 20 mΩ | CMOS | YES | Active LOW | 4-Ball, WLCSP with Backside Laminate, 0.5 mm Pitch |

Application Diagram

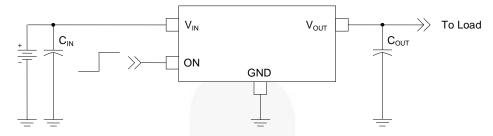


Figure 2. Typical Application

Notes:

- 1. $C_{IN}=1 \mu F$, X5R, 0603, for example Murata GRM185R60J105KE26.
- 2. $C_{OUT}=1 \mu F$, X5R, 0805, for example Murata GRM216R61A105KA01.

Pin Configurations



Figure 3. 1 x 1 mm WLCSP Bumps Facing Down

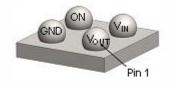


Figure 4. 1 x 1 mm WLCSP Bumps Facing Up

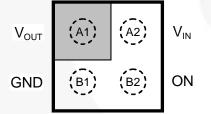


Figure 5. Pin Assignments (Top View)

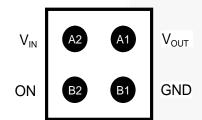


Figure 6. Pin Assignments (Bottom View)

Pin Definitions

| Pin# | Name | Description | | | |
|------|-----------|---|--|--|--|
| A1 | V_{OUT} | Switch Output | | | |
| A2 | V_{IN} | Supply Input; Input to the Power Switch | | | |
| B1 | GND | Ground | | | |
| B2 | ON | ON/OFF Control | | | |

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Paramete | Min. | Max. | Unit | | |
|------------------|---|--------------------------------------|------|------|------|--|
| V _{IN} | V _{IN} , V _{OUT} , V _{ON} to GND | | -0.3 | 4.0 | V | |
| I _{SW} | Maximum Continuous Switch Current | | | 1.5 | Α | |
| P _D | Power Dissipation at T _A =25°C | | | 1.0 | W | |
| T _{STG} | Storage Junction Temperature | | -65 | +150 | °C | |
| T _A | Operating Temperature Range | | -40 | +85 | °C | |
| 0 | Thermal Resistance, Junction-to-Ambient | 1S2P with 1 Thermal Via | | 95 | °C/W | |
| Θ_{JA} | Thermal Resistance, Junction-to-Ambient | 1S2P without Thermal Via | | 187 | C/VV | |
| ESD | Electrostatic Discharge Canability | Human Body Model, JESD22-A114 | 4 | | kV | |
| ESD | Electrostatic Discharge Capability | Charged Device Model, JESD22-C101 | 2 | | K V | |

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

| Symbol | Parameter | Min. | Max. | Unit |
|----------------|-------------------------------|------|------|------|
| V_{IN} | Supply Voltage | 1.0 | 3.6 | V |
| T _A | Ambient Operating Temperature | -40 | +85 | °C |

Electrical Characteristics

Unless otherwise noted, V_{IN} =1.0 to 3.6 V, T_A =-40 to +85°C; typical values are at V_{IN} =3.3 V and T_A =25°C.

| Symbol | Parameter | | Conditions | Min. | Тур. | Max. | Units | |
|----------------------|--|---|---|------|------|----------|-----------|--|
| Basic Op | eration | | | | | <u> </u> | | |
| V _{IN} | Supply Voltage | | | 1.0 | | 3.6 | V | |
| I _{Q(OFF)} | Off Supply | FPF1504 | V _{ON} =GND, V _{OUT} =Open | | 0.25 | | | |
| | Current | FPF1504L | V _{ON} = V _{IN} , V _{OUT} =Open | | 0.3 | | | |
| | Off Switch | FPF1504 | V _{ON} =GND, V _{OUT} =GND | | 0.25 | | μΑ | |
| I _{SD(OFF)} | Current | FPF1504L | V _{ON} = V _{IN} , V _{OUT} =GND | | 0.3 | | | |
| | | EDE4504 | I _{OUT} =0 mA, V _{IN} =3.6 V, V _{ON} =V _{IN} | | 0.08 | | | |
| | Quiescent | FPF1504 | I _{OUT} =0 mA, V _{ON} =V _{IH(MIN)} | | 0.75 | | | |
| ΙQ | Current | EDE15041 | I _{OUT} =0 mA, V _{IN} =3.6 V, V _{ON} =GND | / | 0.08 | | | |
| | / | FPF1504L | I _{OUT} =0 mA, V _{ON} =V _{IL(MAX)} | | 0.95 | | | |
| - 7 | | | V_{IN} =3.3 V, I_{OUT} =200 mA, T_A =25°C | ζ | 15 | 30 | | |
| | | | V _{IN} =1.8 V, I _{OUT} =200 mA, T _A =25°C | | 20 | 40 | mΩ | |
| Ron | On Resistance | | V _{IN} =1.5 V, I _{OUT} =200 mA, T _A =25°C | | 30 | | | |
| | | | V_{IN} =1.0 V, I_{OUT} =200 mA, T_A =25°C | | 40 | 80 | | |
| | | | V _{IN} =1.8 V, I _{OUT} =200 mA, T _A =85°C ⁽³⁾ | | 35 | 50 | | |
| R _{PD} | Output Discharge Pull-Down Resistance Von=0 V or V _{IN} , I _{OUT} =- | | V _{ON} =0 V or V _{IN} , I _{OUT} =-20 mA | | 65 | 95 | Ω | |
| V _{IH} | On Input Logic High Voltage | FPF1504 | | 0.8 | | | | |
| V _{IL} | On Input Logic Low Voltage | FPF1504 | | | | 0.3 | V | |
| I _{ON} | On Input Leakage | | V _{ON} =V _{IN} or GND | 7 | | 1 | μΑ | |
| Dynamic | Characteristics | | | - // | I | 1 | | |
| t _{DON} | Turn-On Delay ⁽⁴⁾ | FPF1504 | | | 80 | , y | | |
| t _R | V _{OUT} Rise Time ⁽⁴⁾ | FPF1504 | R_L =10 Ω , C_L =0.1 μ F, V_{IN} =3.3 V , T_A =25°C | | 130 | | μs | |
| t _{ON} | Turn-On Time ⁽⁴⁾ | FPF1504 | | | 210 | | | |
| | Turn-On | FPF1504 | | | 70 | 100 | J 1 | |
| t _{DON} | Delay ⁽⁴⁾ | FPF1504L | | | 95 | | | |
| | Vout Rise | FPF1504 R _I =500 Ω, C _I | R_L =500 Ω, C_L =0.1 μF, V_{IN} =3.3 V, | | 110 | 150 | | |
| t _R | V _{OUT} Rise Time ⁽⁴⁾ | FPF1504L | T _A =25°C | | 115 | | - μs - | |
| | T (4) | FPF1504 | | | 180 | 250 | | |
| t _{ON} | Turn-On Time ⁽⁴⁾ | FPF1504L |] | | 210 | | | |

Continued on the following page...

Electrical Characteristics (Continued)

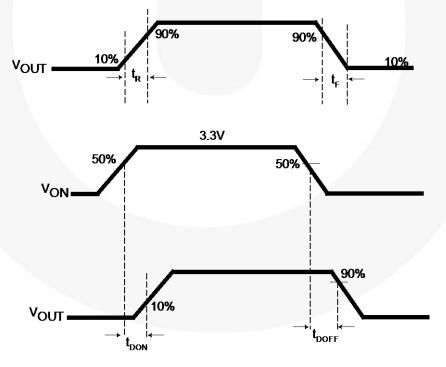
Unless otherwise noted, V_{IN} =1.0 to 3.6 V, T_A =-40 to +85°C; typical values are at V_{IN} =3.3 V and T_A =25°C.

| Symbol | Parameter | | Conditions | Min. | Тур. | Max. | Units | | |
|------------------------|--|------------------------------|--|------|------|------|-------|--|--|
| Dynamic | Dynamic Characteristics (Continued) | | | | | | | | |
| t _{DOFF} | Turn-Off Delay ⁽⁴⁾ | FPF1504 | | | 25 | 30 | | | |
| t _F | V _{OUT} Fall Time ⁽⁴⁾ | FPF1504 | R_L =10 Ω, C_L =0.1 μF, V_{IN} =3.3 V, T_A =25°C | | 2 | | μs | | |
| t _{OFF} | Turn-Off Time ⁽⁴⁾ | FPF1504 | | | 27 | | | | |
| 4 | Turn-Off | FPF1504 | | = -, | 25 | | | | |
| t _{DOFF} | Delay ⁽⁴⁾ | elay ⁽⁴⁾ FPF1504L | 100 | 2 | | | | | |
| | t _F V _{OUT} Fall Time ⁽⁴⁾ |)/ F II T: (4) FPF1504 | R _L =500 Ω, C _L =0.1 μF, V _{IN} =3.3 V, | | 12 | | | | |
| ιF | | FPF1504L T | T _A =25°C | | 14 | | μs | | |
| t _{OFF} Turn- | Turn-Off Time ⁽⁴⁾ | FPF1504 | | | 37 | | | | |
| | | FPF1504L | | | 16 | | | | |

Notes:

- 3. This parameter is guaranteed by design and characterization; not production tested.
- 4. t_{DON}/t_{DOFF}/t_R/t_F are defined in Figure 7.
- 5. Output discharge path is enabled during off.

Timing Diagram - FPF1504



Notes:

- 6. $t_{ON}=t_R+t_{DON}$.
- 7. $t_{OFF}=t_F+t_{DOFF}$.

Figure 7. Timing Diagram for FPF1504

Typical Performance Characteristics for FPF1504

Applicable to active high version only.

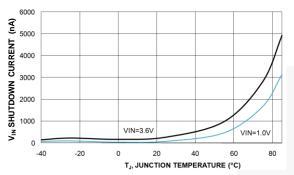
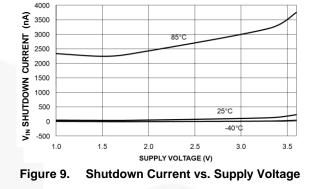


Figure 8. Shutdown Current vs. Temperature



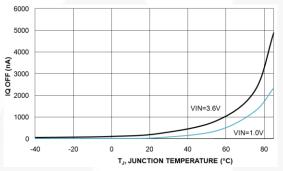


Figure 10. Off Supply Current vs. Temperature

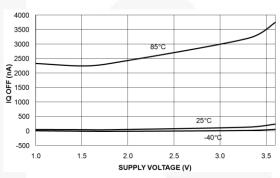


Figure 11. Off Supply Current vs. Supply Voltage

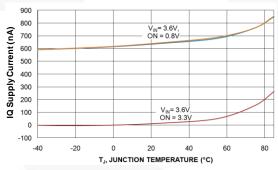


Figure 12. Quiescent Current vs. Temperature

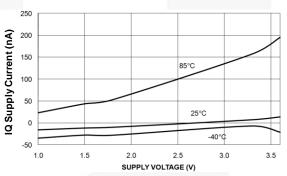


Figure 13. Quiescent Current vs. Supply Voltage (Von=Vin)

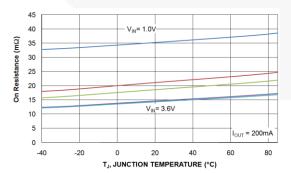


Figure 14. Ron vs. Temperature

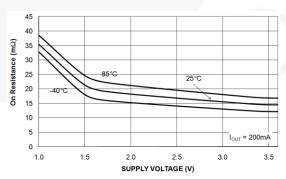


Figure 15. Ron vs. Supply Voltage

Typical Performance Characteristics for FPF1504

Applicable to active high version only.

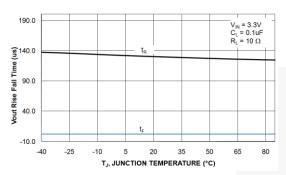


Figure 16. V_{OUT} Rise/Fall Times vs. Temperature (R_L=10 Ω)

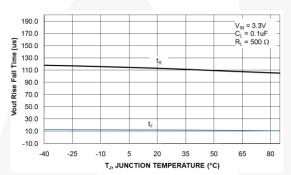


Figure 18. V_{OUT} Rise/Fall Time vs. Temperature $(R_L=500~\Omega)$

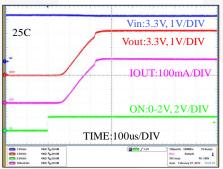


Figure 20. Turn-On Response (V_{IN} =3.3 V, C_{OUT} =0.1 μ F, R_L =10 Ω)

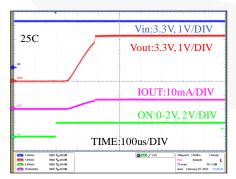


Figure 22. Turn-On Response (V_{IN} =3.3 V, C_{OUT} =0.1 μ F, R_L =500 Ω)

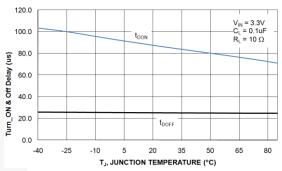


Figure 17. V_{OUT} Turn-On/Turn-Off Delays vs. Temperature (R_L =10 Ω)

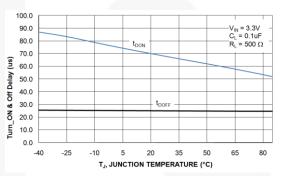


Figure 19. V_{OUT} Turn-On/Turn-Off Delays vs. Temperature (R_L =500 Ω)

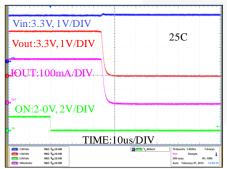


Figure 21. Turn-Off Response (V_{IN} =3.3 V, C_{OUT} =0.1 μ F, R_L =10 Ω)

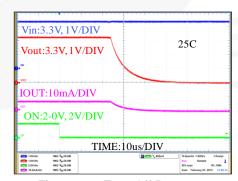


Figure 23. Turn-Off Response (V_{IN} =3.3 V, C_{OUT} =0.1 μ F, R_L =500 Ω)

Application Information

Input Capacitor

IntelliMAXTM switches don't require an input capacitor. To reduce device inrush current, a 0.1 μF ceramic capacitor, C_{IN} , is recommended close to the VIN pin. A higher value of C_{IN} can be used to further reduce the voltage drop experienced as the switch is turned on into a large capacitive load.

Output Capacitor

IntelliMAXTM switches work without an output capacitor. If the applications parasitic board inductance forces V_{OUT} below GND when switching off, a 0.1 μ F capacitor, C_{OUT} , should be placed between V_{OUT} and GND.

Fall Time

Device output fall time can be calculated based on RC constant of external components as follows:

$$t_{\mathsf{F}} = \mathsf{R}_{\mathsf{L}} \times \mathsf{C}_{\mathsf{L}} \times 2.2 \tag{1}$$

where t_F is 90% to 10% fall time, R_L is output, load and C_L is output capacitor.

The same equation works for a device with a pull-down output resistor, then R_L is replaced by a parallel connected pull-down and external output resistor combination, as follows:

$$t_F = \frac{R_L \times R_{PD}}{R_L + R_{PD}} \times C_L \times 2.2 \tag{2}$$

where t_F is 90% to 10% fall time, R_L is output load, R_{PD} is output pull-down resistor (65 Ω typical), and C_L is the output capacitor.

Recommended Land Pattern and Layout

For best thermal performance and minimal inductance and parasitic effects, it is recommended to keep input and output traces short and the capacitors as close to the device as possible. Below is a recommended layout for this device to achieve optimum performance.

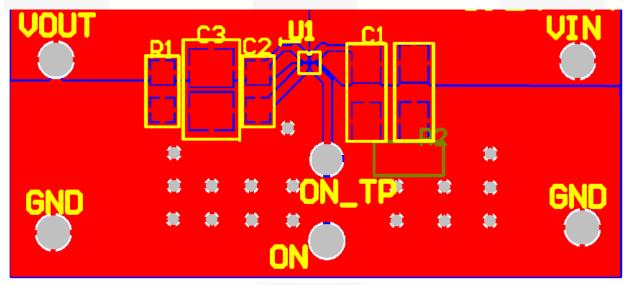
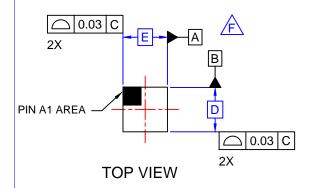


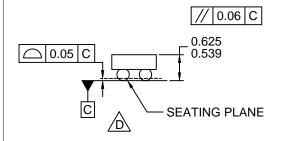
Figure 24. Recommended Land Pattern and Layout

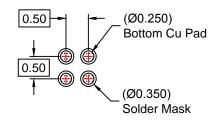
The following information applies to the WLCSP package dimensions on the next page:

Product-Specific Dimensions

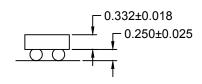
| Product | D | E | х | Y |
|--------------|---------------|---------------|----------|-------------|
| FPF1504UCX | | | | |
| FPF1504BUCX | 060 um 130 um | 060 20 | 0.000 | 0.230 mm |
| FPF1504LUCX | 960 μm ±30 μm | 960 μm ±30 μm | 0.230 mm | 0.230 11111 |
| FPF1504LBUCX | | 19 | | |



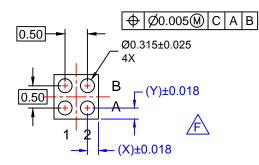




RECOMMENDED LAND PATTERN (NSMD PAD TYPE)



SIDE VIEWS



BOTTOM VIEW

NOTES:

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
- E. PACKAGE NOMINAL HEIGHT IS 582 MICRONS ±43 MICRONS (539-625 MICRONS).
- F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.
- G. DRAWING FILENAME: MKT-UC004ABrev3.



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